

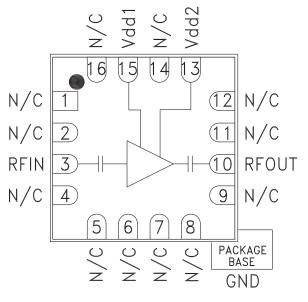


Typical Applications

The HMC451LP3(E) is ideal for:

- Microwave Radio & VSAT
- Military & Space
- Test Equipment & Sensors
- Fiber Optics
- LO Driver for HMC Mixers

Functional Diagram



HMC451LP3 / 451LP3E

GaAs PHEMT MMIC MEDIUM POWER AMPLIFIER, 5 - 18 GHz

Features

Gain: 18 dB Saturated Power: +21 dBm @ 18% PAE Output IP3: +28 dBm Single Supply: +5V @ 120 mA 50 Ohm Matched Input/Output 16 Lead 3x3mm SMT Package: 9mm²

General Description

The HMC451LP3(E) is an efficient GaAs PHEMT MMIC Medium Power Amplifier housed in a leadless RoHS compliant SMT package. Operating between 5 and 18 GHz, the amplifier provides 18 dB of gain, +21 dBm of saturated power and 18% PAE from a single +5V supply. This 50 Ohm matched amplifier does not require any external components and the RF I/O's are DC blocked, making it an ideal linear gain block or LO driver for HMC mixers. The HMC451LP3(E) eliminates the need for wire bonding, and allows the use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25^{\circ}$ C, $Vdd_1 = Vdd_2 = +5V$

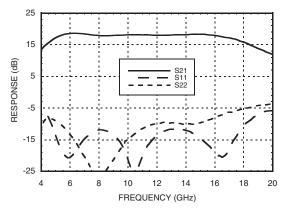
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	5 - 16		16 - 18			GHz	
Gain	15	18		12.5	16		dB
Gain Variation Over Temperature		0.02	0.03		0.02	0.03	dB/ °C
Input Return Loss		13			13		dB
Output Return Loss		12			8		dB
Output Power for 1 dB Compression (P1dB)	16.5	19.5		16	19		dBm
Saturated Output Power (Psat)		21			20		dBm
Output Third Order Intercept (IP3)		28			25		dBm
Noise Figure		7			7		dB
Supply Current (Idd)		120	150		120	150	mA

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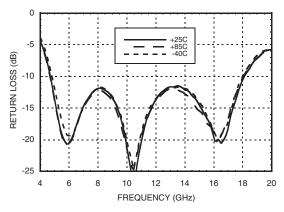




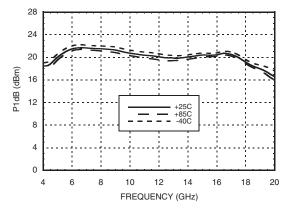
Broadband Gain & Return Loss



Input Return Loss vs. Temperature



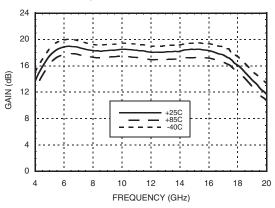
P1dB vs. Temperature



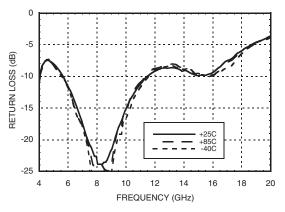
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GaAs PHEMT MMIC MEDIUM POWER AMPLIFIER, 5 - 18 GHz

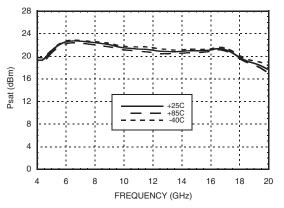
Gain vs. Temperature



Output Return Loss vs. Temperature



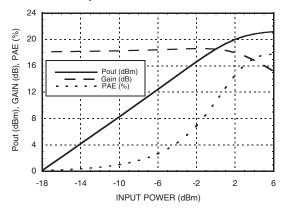




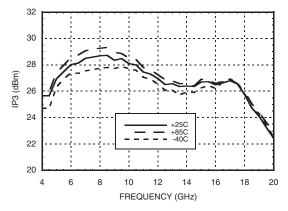




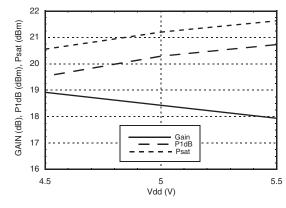
Power Compression @ 10 GHz



Output IP3 vs. Temperature

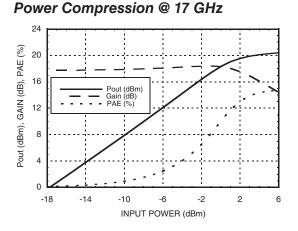


Gain, P1dB & PSAT vs. Supply Voltage @ 11 GHz

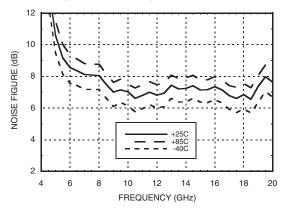


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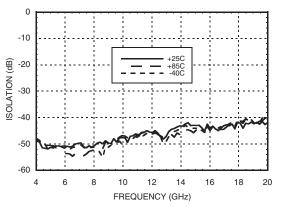
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Noise Figure vs. Temperature



Reverse Isolation vs. Temperature



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Absolute Maximum Ratings

	0
Drain Bias Voltage (Vdd ₁ = Vdd ₂)	+5.5V
RF Input Power (RFIN)(Vdd = +5Vdc)	+10 dBm
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 12.8 mW/°C above 85 °C)	0.83 W
Thermal Resistance (channel to ground paddle)	78 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

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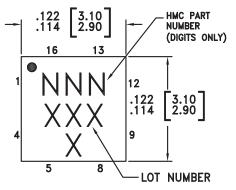
Typical Supply Current vs. Vdd₁ = Vdd₂

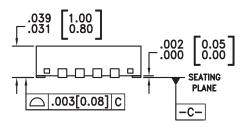
$Vdd_1 = Vdd_2 (V)$	Idd ₁ + Idd ₂ (mA)
+4.5	120
+5.0	122
+5.5	124

Note: Amplifier will operate over full voltage range shown above



Outline Drawing





BOTTOM VIEW -.016 [0.40] REF PIN 16 0.30 .012 .007 .008 [0.20] MIN ΠП PIN 1 0.56 0.44 1.56 1.44 .061 .057 1 П П EXPOSED GROUND PADDLE 1.95 .077 .059 MUST BE CONNECTED TO **RF/DC GROUND** SQUARE NOTES

1. LEADFRAME MATERIAL: COPPER ALLOY

2. DIMENSIONS ARE IN INCHES [MILLIMETERS]

3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE

4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.

5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.

6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC451LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1] 451 XXXX	
HMC451LP3E	HMC451LP3E RoHS-compliant Low Stress Injection Molded Plastic		MSL1 ^[2]	<u>451</u> XXXX

[1] Max peak reflow temperature of 235 $^\circ\text{C}$

[2] Max peak reflow temperature of 260 $^\circ\text{C}$

[3] 4-Digit lot number XXXX



RoHS V EARTH FRIEN

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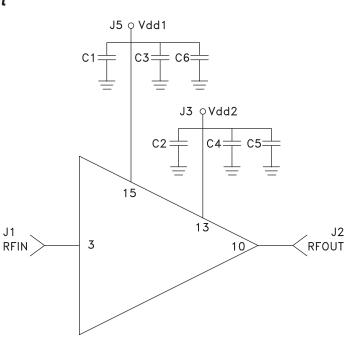
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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 2, 4 - 9, 11, 12, 14, 16	N/C	This pin may be connected to RF/DC ground. Performance will not be affected.	
3	RFIN	This pin is AC coupled and matched to 50 Ohms.	
10	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
13	Vdd2	Power Supply Voltage for the amplifier. External bypass capacitors of 100 pF, 1,000 pF and 2.2 μF are required.	Vdd2
15	Vdd1	Power Supply Voltage for the amplifier. External bypass capacitors of 100 pF, 1,000 pF and 2.2 μF are required.	Vdd1
	GND	Package bottom must be connected to RF/DC ground.	

Application Circuit

Component	Value
C1, C2	100 pF
C3, C4	1,000 pF
C5, C6	2.2 µF



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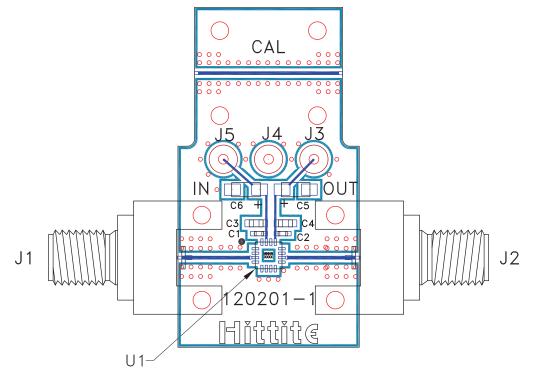


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Evaluation PCB



List of Materials for Evaluation PCB 120202 [1]

Item	Description	
J1 - J2	PCB Mount SMA Connector	
J3 - J5	DC Pin	
C1, C2	100 pF Capacitor, 0402 Pkg.	
C3, C4	1000 pF Capacitor, 0603 Pkg.	
C5, C6	2.2 µF Capacitor, Tantalum	
U1	HMC451LP3(E) Amplifier	
PCB [2]	120201 Evaluation PCB	

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.